

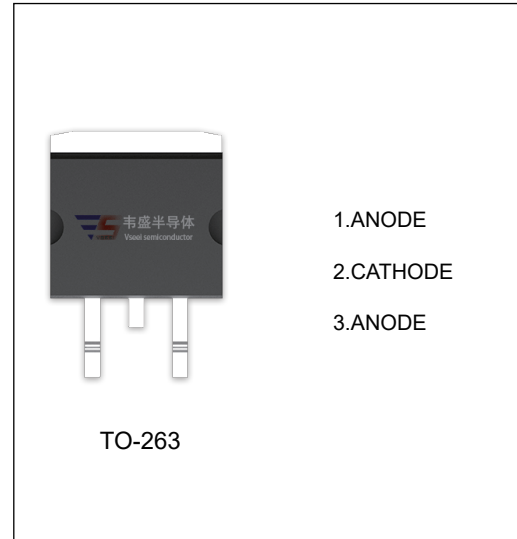
SBDB30100CT SCHOTTKY BARRIER RECTIFIER

MAIN CHARACTERISTICS

I_O	30 (2×15) A
V_{RRM}	100 V
T_j	150 °C
$V_{F(typ)}$	0.70V (@T_j=125°C)

FEATURES

- Low Power Loss,High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop



MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{RRM}	Peak repetitive reverse voltage	100	V
V_{RWM}	Working peak reverse voltage		
V_R	DC blocking voltage		
$V_{R(RMS)}$	RMS reverse voltage	70	V
I_O	Average rectified output current	30	A
I_{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)	200	A
$R_{\theta JC}$	Thermal resistance from junction to case ,T _c =25°C	2.0	°C/W
$R_{\theta JA}$	Thermal resistance from junction to ambient	62.5	°C/W
T_j	Junction temperature	150	°C
T_{stg}	Storage temperature	-55~+150	°C

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=0.1mA$	100			V
Reverse current	I_R	$V_R=100V$	T _j =25°C	5.0	100	uA
			T _j =125°C	5.0		mA
Forward voltage	V_F	$I_F=10A$	T _j =25°C	0.77		V
			T _j =125°C	0.64		V
		$I_F=15A$	T _j =25°C	0.82	0.85	V
			T _j =125°C	0.70		V

*Pulse test: pulse width ≤300μs, duty cycle≤ 2.0%.

FIG.1: FORWARD CURRENT DERATING CURVE

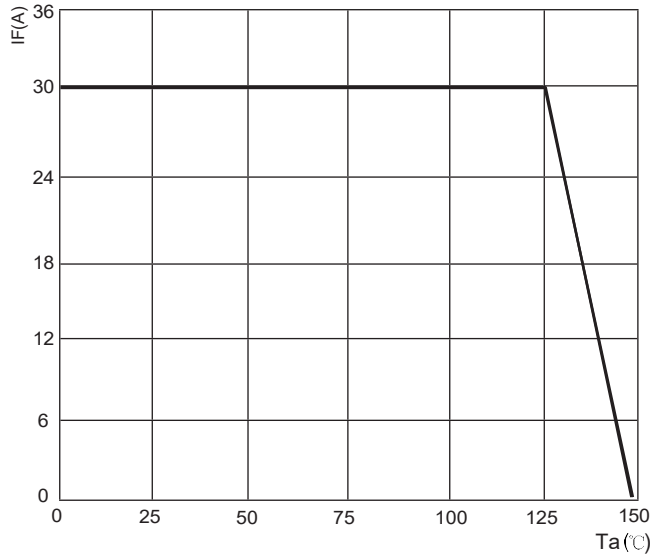


FIG.2: TYPICAL FORWARD CHARACTERISTICS

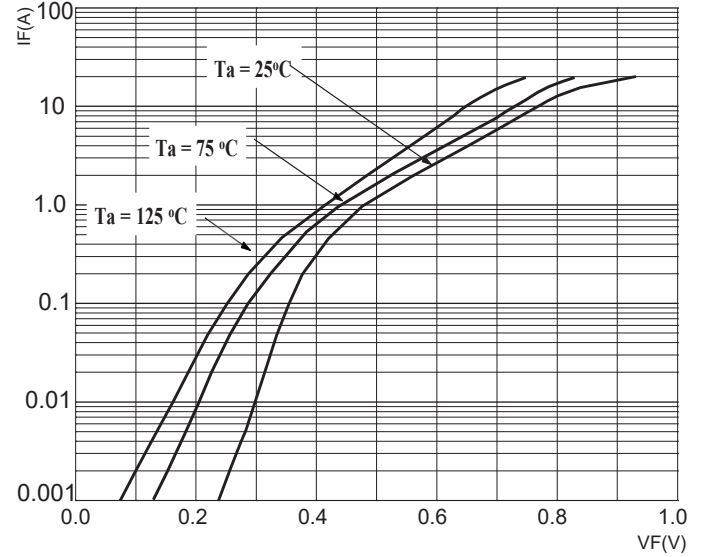


FIG.3: TOTAL CAPACITANCE DERATING CURVE

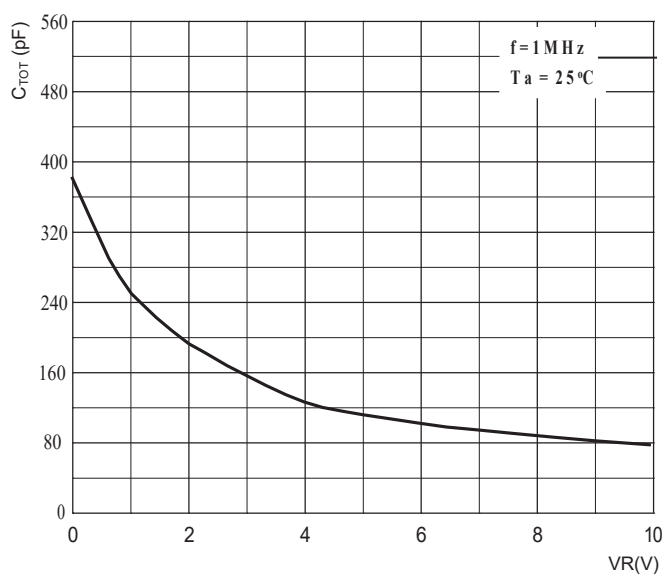


FIG.4: TYPICAL REVERSE CHARACTERISTICS

